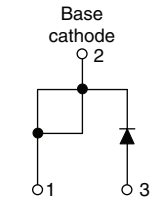
Schottky Rectifier, 10 A

TO-220AC



FEATURES

- 150 °C T_J operation
- TO-220 and D^2PAK packages
- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Lead (Pb)-free ("PbF" suffix)
- Designed and qualified for industrial level

Pb-free Available

RoHS* COMPLIANT

DESCRIPTION

This Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

PRODUCT SUMMARY	
$I_{F(AV)}$	10 A
V_R	35/45 V
I_{RM}	15 mA at 125 °C

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	**CHARACTERISTICS**	**VALUES**	**UNITS**
$I_{F(AV)}$	Rectangular waveform	10	A
I_{FRM}	T_C = 135 °C	20	
V_{RRM}		35/45	V
I_{FSM}	t_p = 5 µs sine	1060	A
V_F	10 Apk, T_J = 125 °C	0.57	V
T_J	Range	- 65 to 150	°C

VOLTAGE RATINGS				
PARAMETER	**SYMBOL**	**MBR1035PbF**	**MBR1045PbF**	**UNITS**
Maximum DC reverse voltage	V_R	35	45	V
Maximum working peak reverse voltage	V_{RWM}			

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**VALUES**	**UNITS**
Maximum average forward current	$I_{F(AV)}$	T_C = 135 °C, rated V_R		10	A
Peak repetitive forward current	I_{FRM}	Rated V_R, square wave, 20 kHz, T_C = 135 °C		20	
Non-repetitive peak surge current	I_{FSM}	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated V_{RRM} applied	1060	A
		Surge applied at rated load conditions halfwave, single phase, 60 Hz		150	
Non-repetitive avalanche energy	E_{AS}	T_J = 25 °C, I_{AS} = 2 A, L = 4 mH		8	mJ
Repetitive avalanche current	I_{AR}	Current decaying linearly to zero in 1 µs Frequency limited by T_J maximum V_A = 1.5 x V_R typical		2	A

* Pb containing terminations are not RoHS compliant, exemptions may apply

ELECTRICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V_{FM} (1)	20 A	T_J = 25 °C	0.84	V
		10 A	T_J = 125 °C	0.57	
		20 A		0.72	
Maximum instantaneous reverse current	I_{RM} (1)	T_J = 25 °C	Rated DC voltage	0.1	mA
		T_J = 125 °C		15	
Threshold voltage	$V_{F(TO)}$	T_J = T_J maximum		0.354	V
Forward slope resistance	r_t			17.6	mΩ
Maximum junction capacitance	C_T	V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 °C		600	pF
Typical series inductance	L_S	Measured from top of terminal to mounting plane		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V_R		10 000	V/µs

Note

(1) Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS

PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction temperature range		T_J		- 65 to 150	°C
Maximum storage temperature range		T_{Stg}		- 65 to 175	
Maximum thermal resistance, junction to case		R_{thJC}	DC operation	2.0	°C/W
Typical thermal resistance, case to heatsink		R_{thCS}	Mounting surface, smooth and greased (only for TO-220)	0.50	
Approximate weight				2	g
				0.07	oz.
Mounting torque	minimum			6 (5)	kgf · cm (lbf · in)
	maximum			12 (10)	
Marking device			Case style TO-220AC	MBR1045	

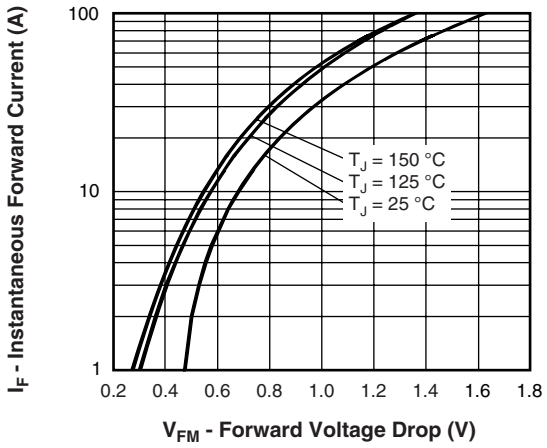


Fig. 1 - Maximum Forward Voltage Drop Characteristics

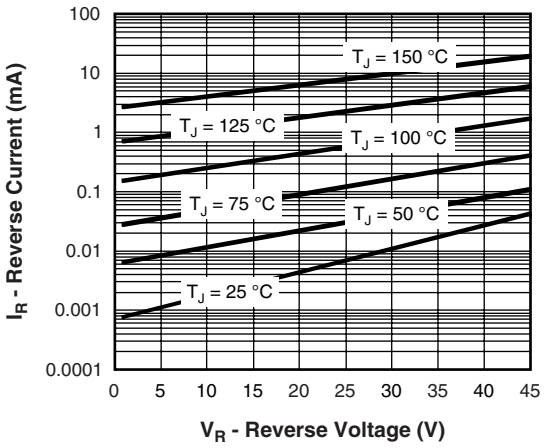


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

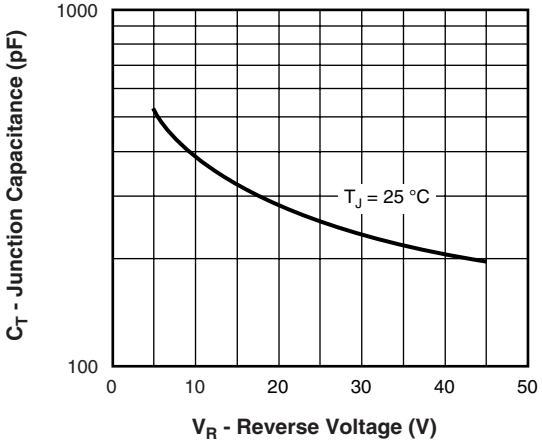


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

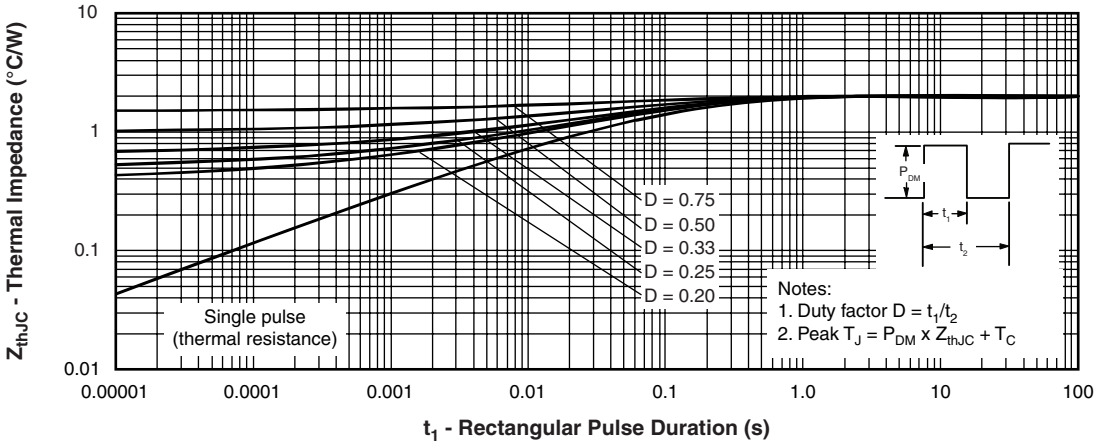


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

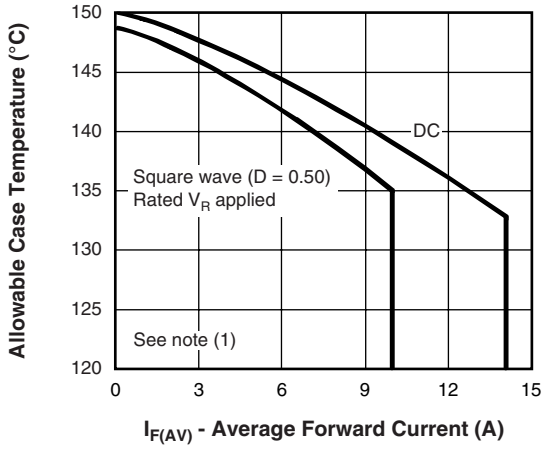


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

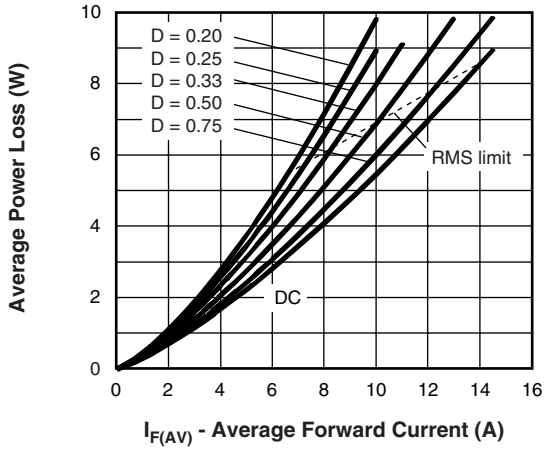


Fig. 6 - Forward Power Loss Characteristics

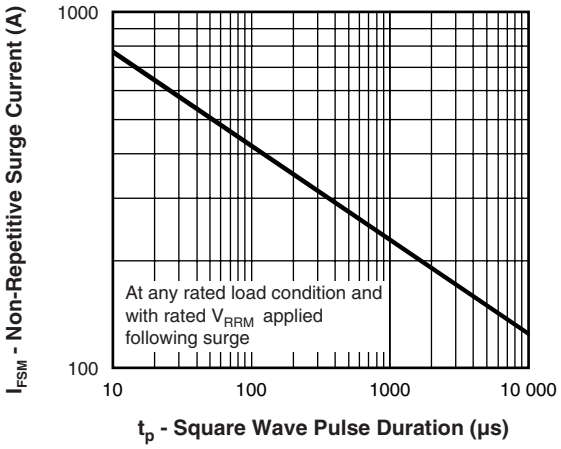


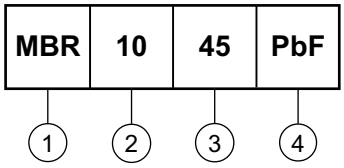
Fig. 7 - Maximum Non-Repetitive Surge Current

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}$/D) (see fig. 6);
Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = Rated V_R

ORDERING INFORMATION TABLE

Device code



1 - Schottky MBR series

2 - Currrent rating (10 = 10 A)

3 - Voltage ratings (35 = 35 V, 45 = 45 V)

4 - • None = Standard production
• PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS	
Dimensions	http://www.vishay.com/doc?95221
Part marking information	http://www.vishay.com/doc?95216
SPICE model	http://www.vishay.com/doc?95293

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